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## FDB86135

### N-Channel Shielded Gate PowerTrench® MOSFET

100V, 176A, 3.5mΩ

#### Features

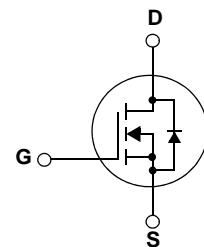
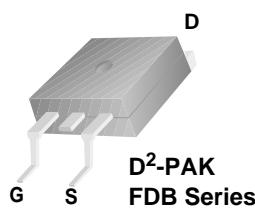
- Shielded Gate MOSFET Technology
- Max  $R_{DS(on)} = 3.5\text{m}\Omega$  at  $V_{GS} = 10\text{V}$ ,  $I_D = 75\text{A}$
- Fast Switching Speed
- Low Gate Charge
- High Performance Trench Technology for Extremely Low  $R_{DS(on)}$
- High Power and Current Handling Capability
- RoHS Compliant

#### General Description

This N-Channel MOSFET is produced using Fairchild Semiconductor's advanced PowerTrench® process that incorporates Shielded Gate technology. This process has been optimized for the on-state resistance and yet maintain superior switching performance.

#### Applications

- DC-DC primary bridge
- DC-DC Synchronous rectification
- Hot swap



#### MOSFET Maximum Ratings $T_C = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter		Ratings	Units
$V_{DSS}$	Drain to Source Voltage		100	V
$V_{GSS}$	Gate to Source Voltage		$\pm 20$	V
$I_D$	Drain Current	- Continuous (Silicon Limited) $T_C = 25^\circ\text{C}$	176	A
		- Continuous (Package Limited) $T_C = 25^\circ\text{C}$	120	
	- Continuous	$T_C = 25^\circ\text{C}$ (Note 1a)	75	
	- Pulsed		704	
$E_{AS}$	Single Pulsed Avalanche Energy (Note 3)		658	mJ
$P_D$	Power Dissipation	- $T_C = 25^\circ\text{C}$ (Note 1a)	227	W
		- $T_A = 25^\circ\text{C}$ (Note 1b)	2.4	$\text{W}/^\circ\text{C}$
$T_J, T_{STG}$	Operating and Storage Temperature Range		-55 to +175	$^\circ\text{C}$

#### Thermal Characteristics

Symbol	Parameter		Ratings	Units
$R_{\theta JC}$	Thermal Resistance, Junction to Case	(Note 1)	0.66	$^\circ\text{C}/\text{W}$
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1a)	62.5	

#### Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDB86135	FDB86135	D2-PAK	330mm	24mm	800

## Electrical Characteristics $T_C = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Units
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### Off Characteristics

$\text{BV}_{\text{DSS}}$	Drain to Source Breakdown Voltage	$I_D = 250\mu\text{A}$ , $V_{GS} = 0\text{V}$ , $T_C = 25^\circ\text{C}$	100	-	-	V
$\Delta \text{BV}_{\text{DSS}}$ $\Delta T_J$	Breakdown Voltage Temperature Coefficient	$I_D = 250\mu\text{A}$ , Referenced to $25^\circ\text{C}$	-	0.07	-	$\text{V}^\circ\text{C}$
$I_{\text{DSS}}$	Zero Gate Voltage Drain Current	$V_{DS} = 80\text{V}$ , $V_{GS} = 0\text{V}$	-	-	1	$\mu\text{A}$
$I_{\text{GSS}}$	Gate to Body Leakage Current	$V_{GS} = \pm 20\text{V}$ , $V_{DS} = 0\text{V}$	-	-	$\pm 100$	nA

### On Characteristics

$V_{GS(\text{th})}$	Gate Threshold Voltage	$V_{GS} = V_{DS}$ , $I_D = 250\mu\text{A}$	2.0	-	4.0	V
$R_{DS(\text{on})}$	Static Drain to Source On Resistance	$V_{GS} = 10\text{V}$ , $I_D = 75\text{A}$	-	3.0	3.5	$\text{m}\Omega$
$g_{FS}$	Forward Transconductance	$V_{DS} = 10\text{V}$ , $I_D = 75\text{A}$	-	167	-	S

### Dynamic Characteristics

$C_{iss}$	Input Capacitance	$V_{DS} = 25\text{V}$ , $V_{GS} = 0\text{V}$ $f = 1\text{MHz}$	-	5485	7295	pF
$C_{oss}$	Output Capacitance		-	2430	3230	pF
$C_{rss}$	Reverse Transfer Capacitance		-	210	-	pF
$Q_{g(\text{tot})}$	Total Gate Charge at $10\text{V}$	$V_{DS} = 80\text{V}$ , $I_D = 75\text{A}$ $V_{GS} = 10\text{V}$	-	89	116	nC
$Q_{gs}$	Gate to Source Gate Charge		-	24	-	nC
$Q_{gs2}$	Gate Charge Threshold to Plateau		-	8	-	nC
$Q_{gd}$	Gate to Drain "Miller" Charge		-	25	-	nC

### Switching Characteristics

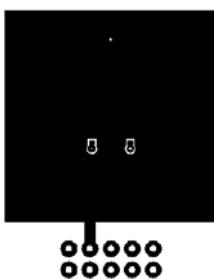
$t_{d(\text{on})}$	Turn-On Delay Time	$V_{DD} = 50\text{V}$ , $I_D = 75\text{A}$ $V_{GS} = 10\text{V}$ , $R_{\text{GEN}} = 4.7\Omega$	-	22	54	ns
$t_r$	Turn-On Rise Time		-	54	118	ns
$t_{d(\text{off})}$	Turn-Off Delay Time		-	37	84	ns
$t_f$	Turn-Off Fall Time		-	11	32	ns

### Drain-Source Diode Characteristics

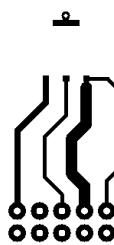
$V_{SD}$	Drain to Source Diode Forward Voltage	$V_{GS} = 0\text{V}$ , $I_{SD} = 75\text{A}$ (Note 2)	-	-	1.25	V
$t_{rr}$	Reverse Recovery Time	$V_{GS} = 0\text{V}$ , $I_{SD} = 75\text{A}$ , $V_{DD} = 80\text{V}$	-	72	-	ns
$Q_{rr}$	Reverse Recovery Charge	$dI_F/dt = 100\text{A}/\mu\text{s}$	-	129	-	nC

#### NOTES:

1.  $R_{0JA}$  is determined with the device mounted on a  $1\text{ in}^2$  pad 2 oz copper pad on a  $1.5 \times 1.5\text{ in.}$  board of FR-4 material.  $R_{0JC}$  is guaranteed by design while  $R_{0CA}$  is determined by the user's board design.



a)  $40^\circ\text{C}/\text{W}$  when mounted on a  $1\text{ in}^2$  pad of 2 oz copper



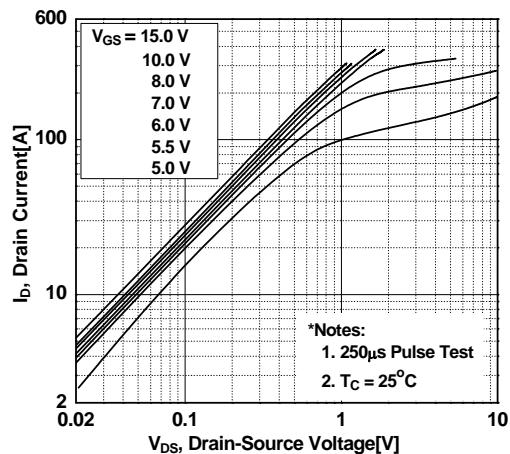
b)  $62.5^\circ\text{C}/\text{W}$  when mounted on a minimum pad of 2 oz copper

2. Pulse Test: Pulse Width  $< 300\ \mu\text{s}$ , Duty cycle  $< 2.0\ %$ .

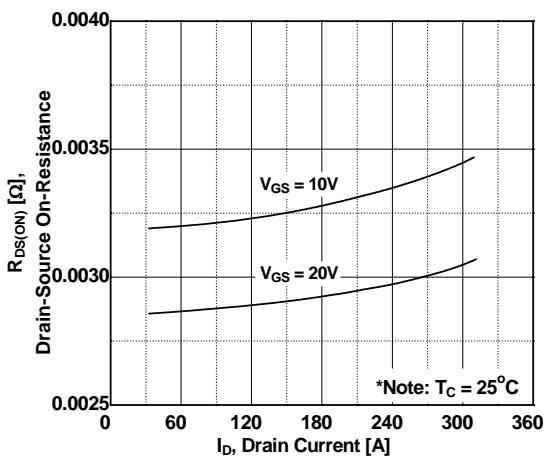
3. Starting  $T_J = 25^\circ\text{C}$ ,  $L = 1\text{ mH}$ ,  $I_{AS} = 36.3\text{ A}$ ,  $V_{DD} = 100\text{ V}$ ,  $V_{GS} = 10\text{ V}$ .

## Typical Performance Characteristics

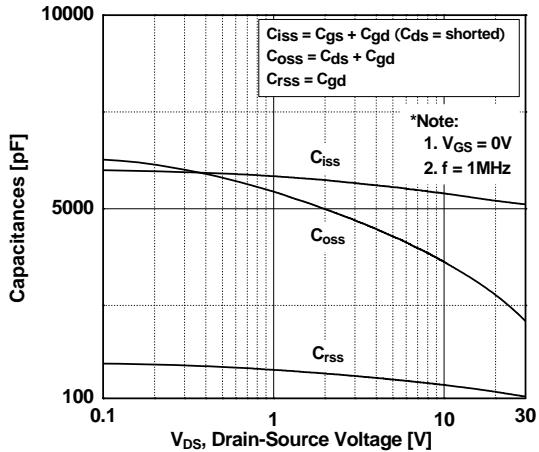
**Figure 1. On-Region Characteristics**



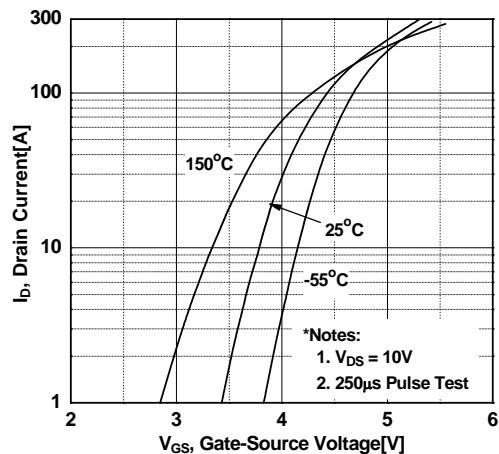
**Figure 3. On-Resistance Variation vs. Drain Current and Gate Voltage**



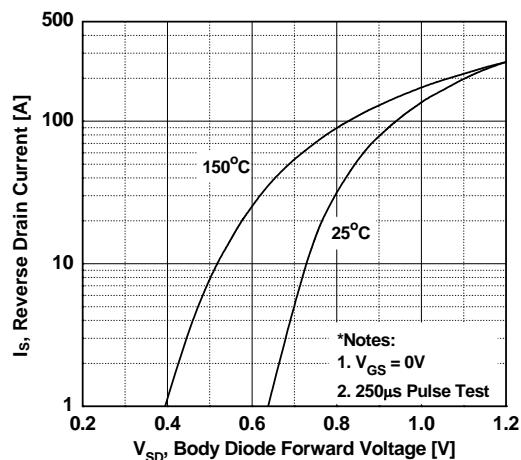
**Figure 5. Capacitance Characteristics**



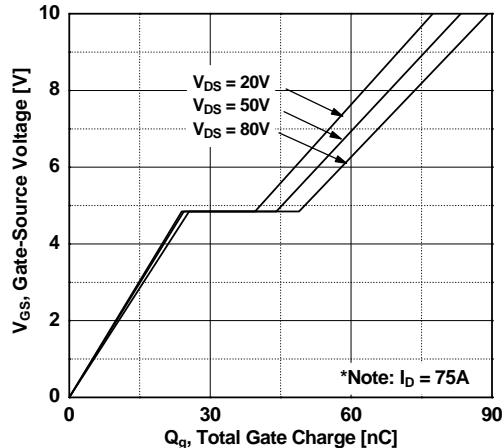
**Figure 2. Transfer Characteristics**



**Figure 4. Body Diode Forward Voltage Variation vs. Source Current and Temperature**

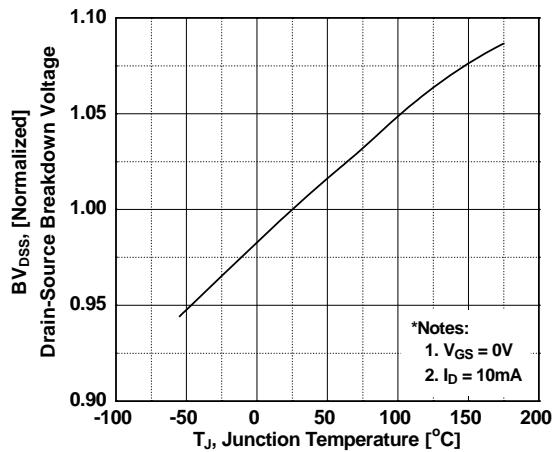


**Figure 6. Gate Charge Characteristics**

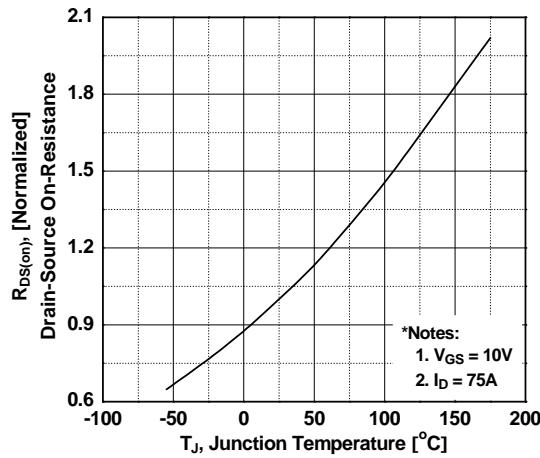


## Typical Performance Characteristics

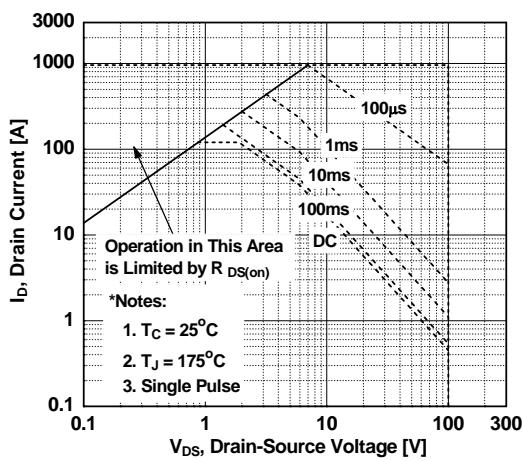
**Figure 7. Breakdown Voltage Variation vs. Temperature**



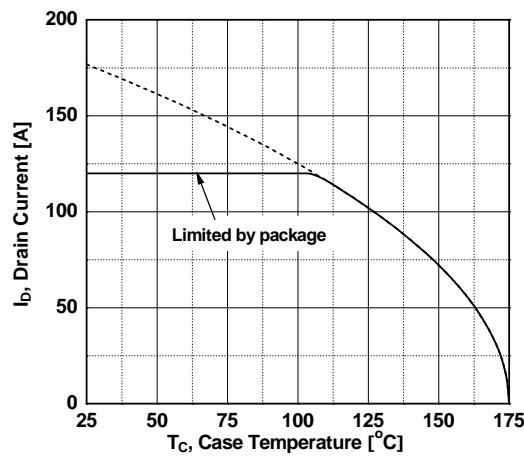
**Figure 8. On-Resistance Variation vs. Temperature**



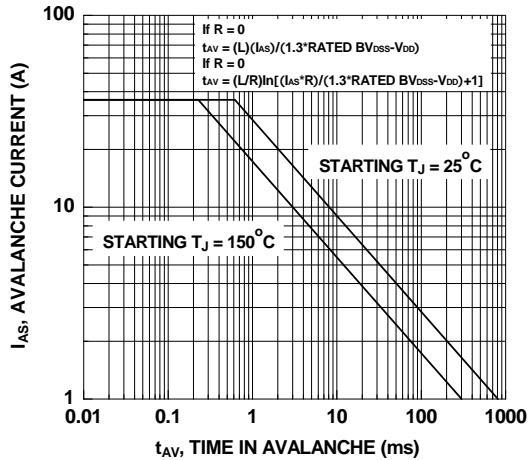
**Figure 9. Maximum Safe Operating Area**



**Figure 10. Maximum Drain Current vs. Case Temperature**

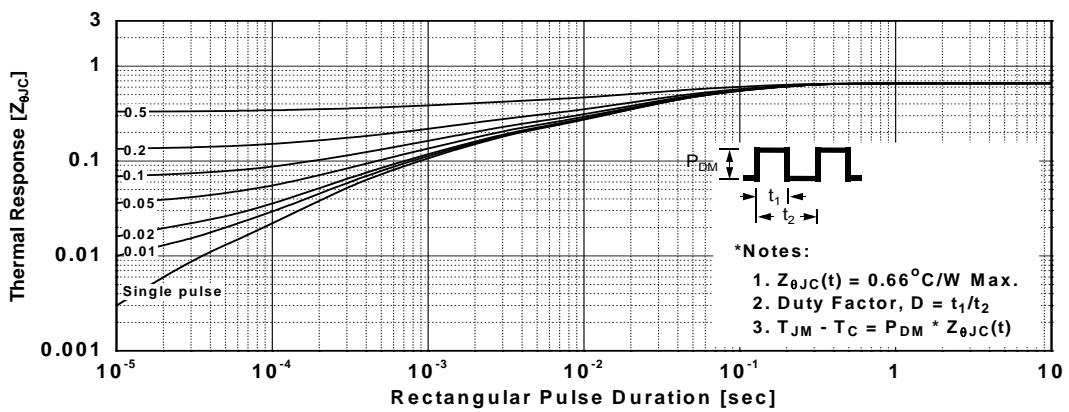


**Figure 11. Unclamped Inductive Switching Capability**

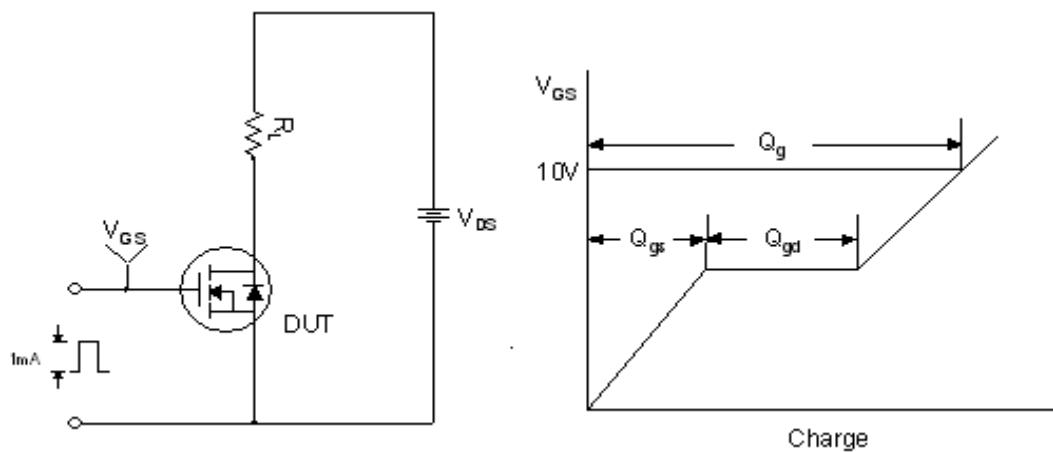


## Typical Performance Characteristics

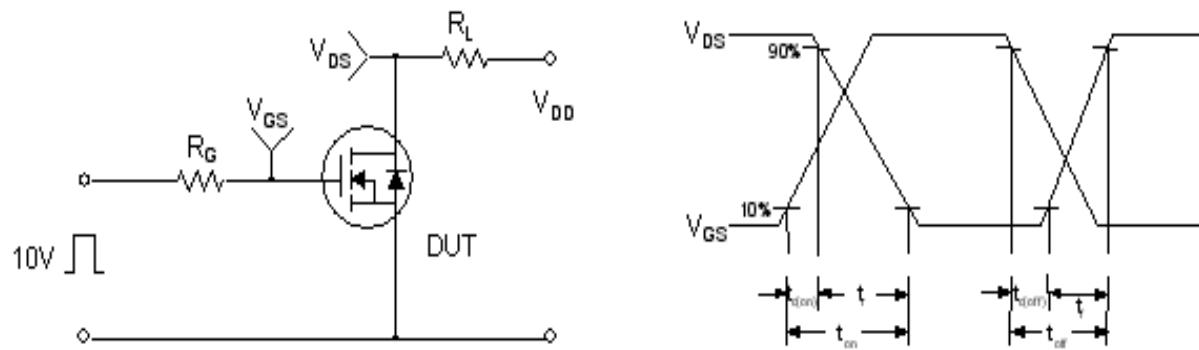
Figure 12. Transient Thermal Response Curve



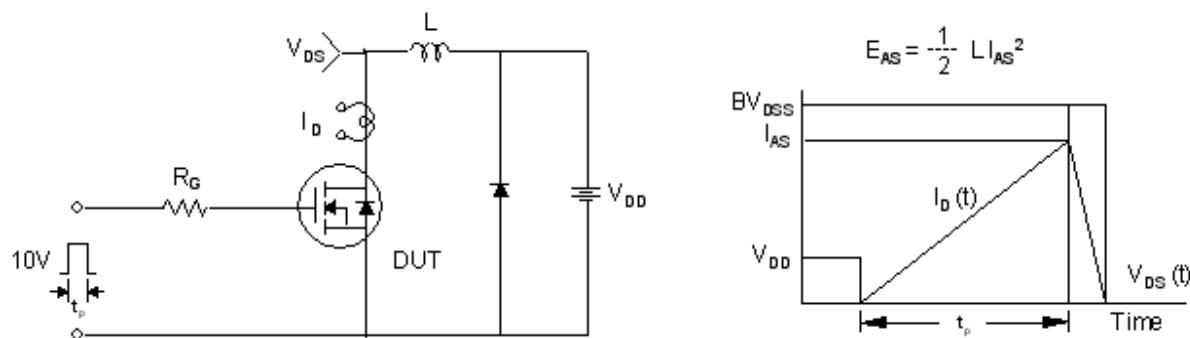
Gate Charge Test Circuit & Waveform



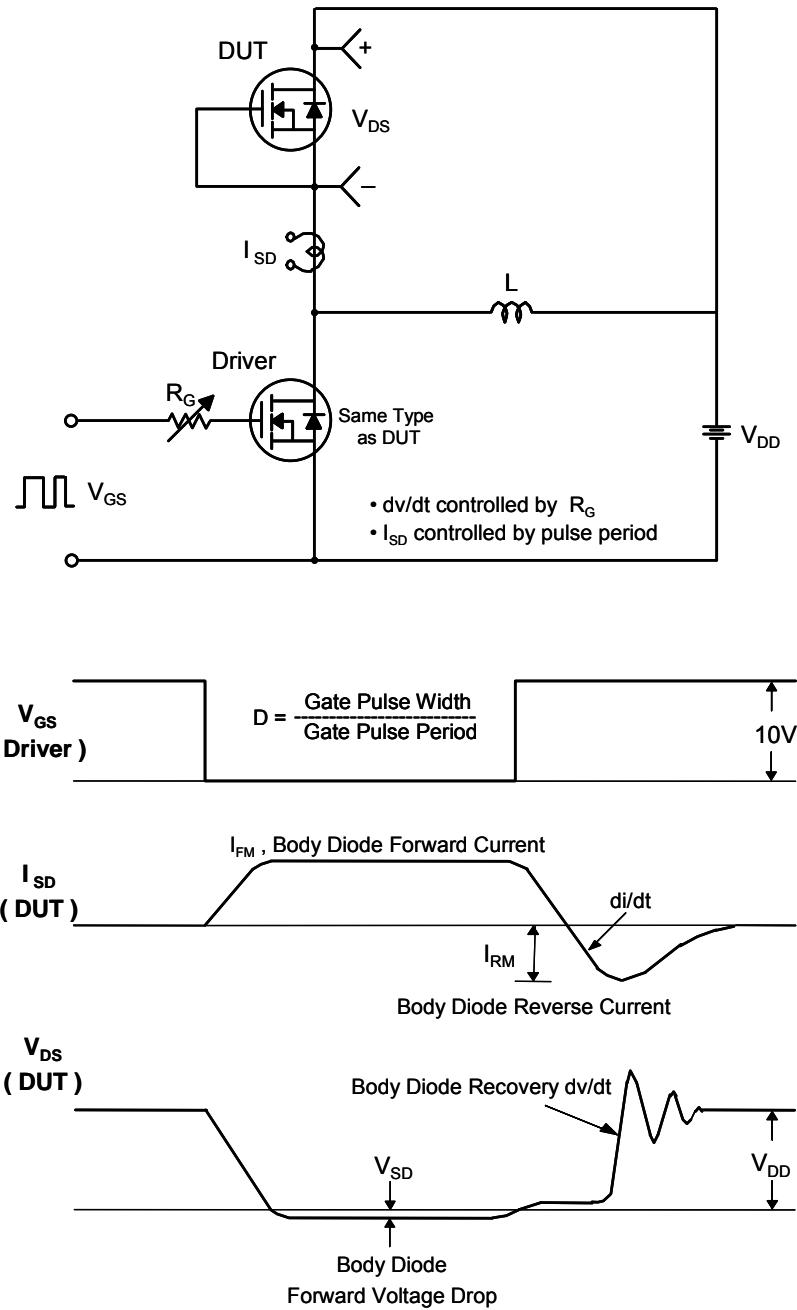
Resistive Switching Test Circuit & Waveforms



Unclamped Inductive Switching Test Circuit & Waveforms

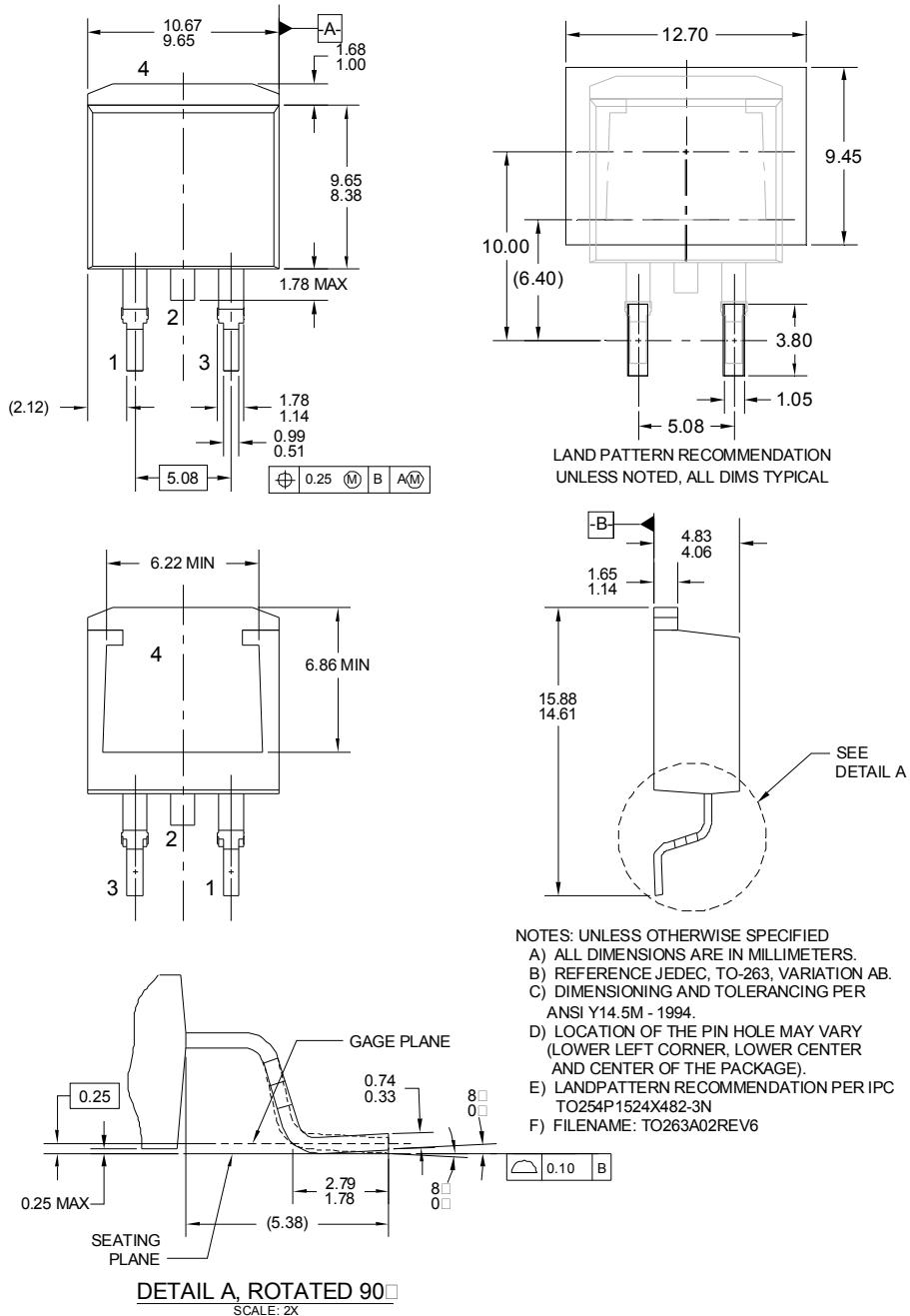


Peak Diode Recovery dv/dt Test Circuit & Waveforms



## Mechanical Dimensions

## D2-PAK



Dimensions in Millimeters



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Разъемы специального, военного и аэрокосмического назначения:

(Применяются в военной, авиационной, аэрокосмической, морской, железнодорожной, горно- и нефтедобывающей отраслях промышленности)

«FORSTAR» (основан в 1998 г.)

ВЧ соединители, коаксиальные кабели, кабельные сборки и микроволновые компоненты:

(Применяются в телекоммуникациях гражданского и специального назначения, в средствах связи, РЛС, а так же военной, авиационной и аэрокосмической отраслях промышленности).



Телефон: 8 (812) 309-75-97 (многоканальный)

Факс: 8 (812) 320-03-32

Электронная почта: ocean@oceanchips.ru

Web: <http://oceanchips.ru/>

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, д. 2, корп. 4, лит. А